

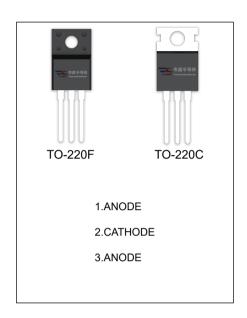
# SBD10100SCTB SBDF10100SCTB SCHOTTKY BARRIER RECTIFIER

#### MAIN CHARACTERISTICS

| Io               | 10 (2×5) A       |
|------------------|------------------|
| V <sub>RRM</sub> | 100 V            |
| T <sub>j</sub>   | 150 ℃            |
| $V_{F(typ)}$     | 0.54V (@Tj=125℃) |

### **FEATURES**

- Low Power Loss, High Efficiency
- Guard Ring Die Construction for Transient Protection
- High Current Capability and Low Forward Voltage Drop



# MAXIMUM RATINGS ( T<sub>a</sub>=25℃ unless otherwise noted )

| Cumbal              | Parameter  | SE       | Unit       |            |  |
|---------------------|--|----------|------------|------------|--|
| Symbol              | Parameter  |          | F10100SCTB | Unit       |  |
| V <sub>RRM</sub>    | Peak repetitive reverse voltage                                  |          |            |            |  |
| V <sub>RWM</sub>    | Working peak reverse voltage                                     | 100      |            | V          |  |
| V <sub>R</sub>      | DC blocking voltage  |          |            |            |  |
| V <sub>R(RMS)</sub> | RMS reverse voltage  | 70       |            | V          |  |
| lo                  | Average rectified output current                                 | 10       |            | Α          |  |
| I <sub>FSM</sub>    | Non-Repetitive peak forward surge current (8.3ms half sine wave) | 150      |            | Α          |  |
| R <sub>⊝Jc</sub>    | Thermal resistance from junction to case ,Tc=25℃                 | 2.0      | 3.0        | °C/W       |  |
| R <sub>OJA</sub>    | Thermal resistance from junction to ambient                      | 62.5     |            | °C/W       |  |
| Tj                  | Junction temperature   | 150      |            | °C         |  |
| T <sub>stg</sub>    | Storage temperature  | -55~+150 |            | $^{\circ}$ |  |

## ELECTRICAL CHARACTERISTICS (T₂=25℃ unless otherwise specified)

| Parameter       | Symbol            | Test conditions I <sub>R</sub> =1mA |          | Тур  | Max  | Unit<br>V |
|-----------------|-------------------|-------------------------------------|----------|------|------|-----------|
| Reverse voltage | V <sub>(BR)</sub> |                                     |          |      |      |           |
| Reverse current | I <sub>R</sub>    | V <sub>R</sub> =100V                | Tj =25℃  | 10.0 | 100  | uA        |
|                 | ik ik             |                                     | Tj =125℃ | 5.0  |      | mA        |
| Forward voltage | V <sub>F</sub>    | I <sub>F</sub> =3A                  | Tj =25℃  | 0.50 |      | V         |
|                 |                   |                                     | Tj =125℃ | 0.45 |      | V         |
|                 |                   | I <sub>F</sub> =5A                  | Tj =25℃  | 0.57 | 0.63 | V         |
|                 |                   |                                     | Tj =125℃ | 0.54 |      | V         |

<sup>\*</sup>Pulse test: pulse width ≤300µs, duty cycle≤ 2.0%.



